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Substitute for form 1449A/PTO

**INFORMATION DISCLOSURE
STATEMENT BY APPLICANT**

(Use as many sheets as necessary)

Sheet 1 of 1

Complete if Known

Application Number	10/630,970
Filing Date	07/31/2003
First Named Inventor	DAVID L O'MEARA
Art Unit	2818
Examiner Name	Phuc Dang
Attorney Docket Number	071469-0303786

U. S. PATENT DOCUMENTS

Examiner Initials*	Cite No. ¹	Document Number Number-Kind Code ² (if known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
PD	1	US- 6,258,731 B1	07-10-2001	ANDO	
↓	2	US- 2001/0102859 A1	08-01-2002	YOO	
↓	3	US- 5,296,412	03-22-1994	OHSAWA	
PD	4	US- 2002/111001 A1	08-15-2002	AHN et al.	
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FOREIGN PATENT DOCUMENTS

Examiner Initials*	Cite No. ¹	Foreign Patent Document Country Code ³ Number ⁴ Kind Code ⁵ (if known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	T ⁶

Examiner
Signature

PHUC T. DANG

Date
Considered

9/1/05

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Substitute for form 1449B/PTO		Complete if Known			
INFORMATION DISCLOSURE STATEMENT BY APPLICANT (Use as many sheets as necessary)		Application Number	10/630,970		
		Filing Date	07/31/2003		
		First Named Inventor	DAVID L O'MEARA		
		Art Unit	2818		
		Examiner Name	Phuc Dang		
Sheet	1	of	1	Attorney Docket Number	071469-0303786

NON PATENT LITERATURE DOCUMENTS			
Examiner Initials*	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ²
PD	I	J. DERRIEN, "SiO ₂ Ultra Thin Film Growth Kinetics as Investigated by Surface Techniques," Surface Science, North-Holland Publishing Company, pp. 32-46, (June 1982).	
PD	II	C. RAISIN ET AL., "Work Function Measurements During Growth of Ultra Thin Films of SiO ₂ on Characterized Silicon Surfaces," Solid-State Electronics, Pergamon Press Ltd., Vol. 27 (No. 5), pp. 413-417, (May 1984).	
PD	III	MAHISHA KUNDU ET AL., "Effect of oxygen pressure on the structure and thermal stability of ultrathin Al ₂ O ₃ films on Si (001)," Journal of Applied Physics, American Institute of Physics, Vol. 91 (No. 1), pp. 492-500, (January 1, 2002).	

Examiner Signature	PHUC T. DANG	Date Considered	9/1/05
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